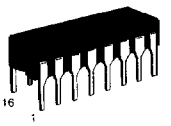
MOTOROLA

MC14174B

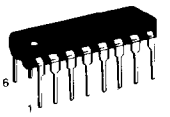
HEX TYPE D FLIP-FLOP

The MC14174B hex type D flip-flop is constructed with MOS P-channel and N-channel enhancement mode devices in a single monolithic structure. Data on the D inputs which meets the setup time requirements is transferred to the Q outputs on the positive edge of the clock pulse. All six flip-flops share common clock and reset inputs. The reset is active low, and independent of the clock.

- Static Operation
- All Inputs and Outputs Buffered
- Diode Protection on All Inputs
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low-power TTL Loads or One Low-Power Schottky TTL Load over the Rated Temperature Range
- Functional Equivalent to TTL 74174



L SUFFIX
CERAMIC
CASE 620



P SUFFIX
PLASTIC
CASE 648

D SUFFIX
SOIC
CASE 751B

ORDERING INFORMATION

MC14XXXBCP Plastic
MC14XXXBCL Ceramic
MC14XXXBD SOIC

T_A = −55° to 125°C for all packages.

MAXIMUM RATINGS* (Voltages Referenced to V_{SS})

Symbol	Parameter	Value	Unit
V_{DD}	DC Supply Voltage	−0.5 to +18.0	V
V_{in}, V_{out}	Input or Output Voltage (DC or Transient)	−0.5 to V_{DD} +0.5	V
I_{in}, I_{out}	Input or Output Current (DC or Transient), per Pin	±10	mA
P_D	Power Dissipation, per Package†	500	mW
T_{stg}	Storage Temperature	−65 to +150	°C
T_L	Lead Temperature (8-Second Soldering)	260	°C

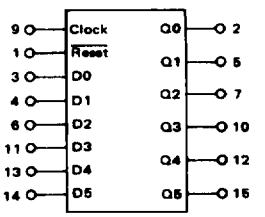
*Maximum Ratings are those values beyond which damage to the device may occur.
†Temperature Derating: Plastic "P and D/DW" Packages: −7.0 mW/°C From 65°C To 125°C
Ceramic "L" Packages: −12 mW/°C From 100°C To 125°C

TRUTH TABLE
(Positive Logic)

INPUTS			OUTPUT	
Clock	Data	$\overline{\text{Reset}}$	Q	
↑	0	1	0	
↑	1	1	1	
↓	X	1	Q	No Change
X	X	0	0	

X = Don't Care

BLOCK DIAGRAM



V_{DD} = Pin 16
V_{SS} = Pin 8

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in}$ or $V_{out}) \leq V_{DD}$.
Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.

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ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

Characteristic	Symbol	V_{DD} Vdc	−55°C Min	−55°C Max	25°C Min	25°C Typ #	25°C Max	125°C Min	125°C Max	Unit
Output Voltage "0" Level V_{in} = V_{DD} or 0	V_{OL}	5.0	—	0.05	—	0	0.05	—	0.05	Vdc
		10	—	0.05	—	0	0.05	—	0.05	
		15	—	0.05	—	0	0.05	—	0.05	
"1" Level V_{in} = 0 or V_{DD}	V_{OH}	5.0	4.95	—	4.95	5.0	—	4.95	—	Vdc
		10	9.95	—	9.95	10	—	9.95	—	
		15	14.95	—	14.95	15	—	14.95	—	
Input Voltage "0" Level (V_O = 4.5 or 0.5 Vdc)	V_{IL}	5.0	—	1.5	—	2.25	1.5	—	1.5	Vdc
(V_O = 9.0 or 1.0 Vdc)		10	—	3.0	—	4.50	3.0	—	3.0	
(V_O = 13.5 or 1.5 Vdc)		15	—	4.0	—	6.75	4.0	—	4.0	
"1" Level (V_O = 0.5 or 4.5 Vdc)	V_{IH}	5.0	3.5	—	3.5	2.75	—	3.5	—	Vdc
(V_O = 1.0 or 9.0 Vdc)		10	7.0	—	7.0	5.50	—	7.0	—	
(V_O = 1.5 or 13.5 Vdc)		15	11	—	11	8.25	—	11	—	
Output Drive Current (V_{OH} = 2.5 Vdc) Source	I_{OH}	5.0	−3.0	—	−2.4	−4.2	—	−1.7	—	mAdc
(V_{OH} = 4.6 Vdc)		5.0	−0.64	—	−0.51	−0.88	—	−0.36	—	
(V_{OH} = 9.5 Vdc)		10	−1.6	—	−1.3	−2.25	—	−0.9	—	
(V_{OH} = 13.5 Vdc)		15	−4.2	—	−3.4	−8.8	—	−2.4	—	
(V_{OL} = 0.4 Vdc) Sink	I_{OL}	5.0	0.64	—	0.51	0.88	—	0.36	—	mAdc
(V_{OL} = 0.5 Vdc)		10	1.6	—	1.3	2.25	—	0.9	—	
(V_{OL} = 1.5 Vdc)		15	4.2	—	3.4	8.8	—	2.4	—	
Input Current	I_{in}	15	—	±0.1	—	±0.00001	±0.1	—	±1.0	μAdc
Input Capacitance (V_{in} = 0)	C_{in}	—	—	—	—	5.0	7.5	—	—	pF
Quiescent Current (Per Package)	I_{DD}	5.0	—	5.0	—	0.005	5.0	—	150	μAdc
		10	—	10	—	0.010	10	—	300	
		15	—	20	—	0.015	20	—	600	
Total Supply Current**† (Dynamic plus Quiescent, Per Package) (C_L = 50 pF on all outputs, all buffers switching)	I_T	5.0	I_T = (1.1 μA/kHz) f + I_{DD}							μAdc
		10	I_T = (2.3 μA/kHz) f + I_{DD}							
		15	I_T = (3.7 μA/kHz) f + I_{DD}							

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#Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

**The formulas given are for the typical characteristics only at 25°C.

†To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50\ pF) + (C_L - 50)\ Vfk$$

where: I_T is in μA (per package), C_L in pF. V = (V_{DD} − V_{SS}) in volts. f in kHz is input frequency, and k = 0.003.

SWITCHING CHARACTERISTICS* (C_L = 50 pF, T_A = 25°C)

Characteristic	Symbol	V_{DD} Vdc	All Types			Unit
			Min	Typ #	Max	
Output Rise and Fall Time	t_{TLH}, t_{THL}					ns
t_{TLH}, t_{THL} = (1.35 ns/pF) C_L + 32 ns		5.0	—	100	200	
t_{TLH}, t_{THL} = (0.6 ns/pF) C_L + 20 ns		10	—	50	100	
t_{TLH}, t_{THL} = (0.4 ns/pF) C_L + 20 ns		15	—	40	80	
Propagation Delay Time — Clock to Q	t_{PLH}, t_{PHL}					ns
t_{PLH}, t_{PHL} = (0.9 ns/pF) C_L + 165 ns		5.0	—	210	400	
t_{PLH}, t_{PHL} = (0.36 ns/pF) C_L + 64 ns		10	—	85	160	
t_{PLH}, t_{PHL} = (0.26 ns/pF) C_L + 52 ns		15	—	65	120	
Propagation Delay Time — $\overline{\text{Reset}}$ to Q	t_{PHL}					ns
t_{PHL} = (0.9 ns/pF) C_L + 205 ns		5.0	—	250	500	
t_{PHL} = (0.36 ns/pF) C_L + 79 ns		10	—	100	200	
t_{PHL} = (0.26 ns/pF) C_L + 62 ns		15	—	75	150	
Clock Pulse Width	t_{WH}	5.0	150	75	—	ns
		10	90	45	—	
		15	70	35	—	
$\overline{\text{Reset}}$ Pulse Width	t_{WL}	5.0	200	100	—	ns
		10	100	50	—	
		15	80	40	—	
Clock Pulse Frequency	f_{cl}	5.0	—	7.0	2.0	MHz
		10	—	12.0	5.0	
		15	—	15.5	6.5	
Clock Pulse Rise and Fall Time	t_{TLH}, t_{THL}	5.0	—	—	15	μs
		10	—	—	5.0	
		15	—	—	4.0	
Data Setup Time	t_{su}	5.0	40	20	—	ns
		10	20	10	—	
		15	15	0	—	
Data Hold Time	t_h	5.0	80	40	—	ns
		10	40	20	—	
		15	30	15	—	
$\overline{\text{Reset}}$ Removal Time	t_{rem}	5.0	250	125	—	ns
		10	100	50	—	
		15	80	40	—	

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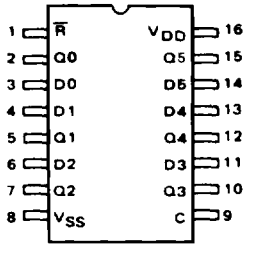
PIN ASSIGNMENT



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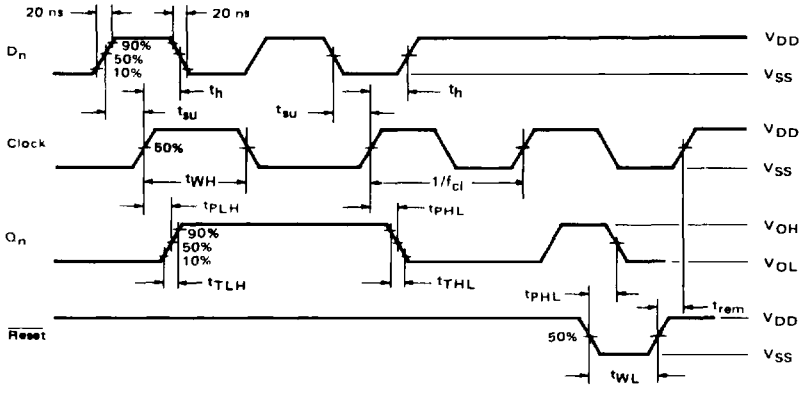
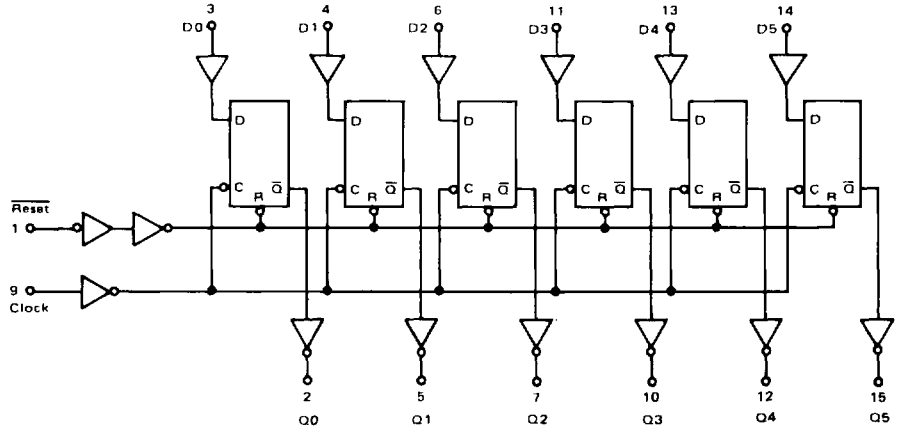
TIMING DIAGRAM



FUNCTIONAL BLOCK DIAGRAM



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